

Polar ™ **Power MOSFET**

IXTA2R4N120P IXTP2R4N120P IXTH2R4N120P

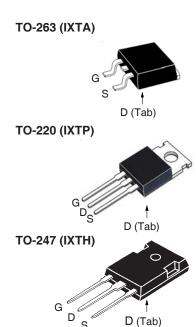
N-Channel Enhancement Mode Avalanche Rated



Symbol	Test Conditions	Maximum	Ratings
V _{DSS}	$T_{_{\rm J}} = 25^{\circ}\text{C to } 150^{\circ}\text{C}$	1200	V
V _{DGR}	$T_{_{ m J}}$ = 25°C to 150°C, $R_{_{ m GS}}$ = 1M Ω	1200	V
V _{GSS}	Continuous	±30	V
V _{GSM}	Transient	±40	V
I _{D25}	T _c = 25°C	2.4	Α
I _{DM}	$T_{\rm c}$ = 25°C, Pulse Width Limited by $T_{\rm JM}$	6.0	Α
I _A	T _C = 25°C	2.4	A
E _{AS}	$T_c = 25^{\circ}C$	200	mJ
dv/dt	$I_{_{\mathrm{S}}} \leq I_{_{\mathrm{DM}}}, V_{_{\mathrm{DD}}} \leq V_{_{\mathrm{DSS}}}, T_{_{\mathrm{J}}} \leq 150^{\circ}\mathrm{C}$	10	V/ns
P_{D}	T _c = 25°C	125	W
T _J		-55 +150	°C
T_{JM}		150	°C
T _{stg}		-55 +150	°C
T _L	Maximum Lead Temperature for Solderi	ing 300	°C
T _{SOLD}	1.6 mm (0.062in.) from Case for 10s	260	°C
F _c	Mounting Force (TO-263) Mounting Torque (TO-220 & TO-247)	1065 / 2.214.6 1.13 / 10	N/lb Nm/lb.in
Weight	TO-263 TO-220 TO-247	2.5 3.0 6.0	g 9

Symbol (T _J = 25°C, U	Test Conditions Unless Otherwise Specified)	Charac Min.	cteristic	Values Max	ζ.
BV _{DSS}	$V_{GS} = 0V, I_D = 250\mu A$	1200			V
$V_{\rm GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.5		4.5	V
I _{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0V$			±100	nΑ
I _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$ $T_{J} = 125^{\circ}C$			5 300	μ Α μ Α
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$		6.5	7.5	Ω

1200V 2.4A D25 7.5Ω $\mathbf{R}_{\mathrm{DS(on)}}$



Features

G = Gate

S = Source

• International Standard Packages

D

= Drain

Tab = Drain

- Low Q_GAvalanche Rated
- Low Package Inductance
- Fast Intrinsic Rectifier

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- DC-DC Converters
- Switch-Mode and Resonant-Mode **Power Supplies**
- AC and DC Motor Drives
- Discharge Circiuts in Lasers, Spark Igniters, RF Generators
- High Voltage Pulse Power Applications



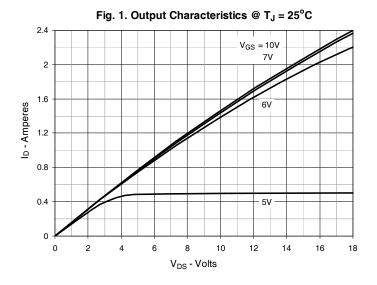
Symbol	Test Conditions		acteristic	
$(1_{J} = 25^{\circ}C, U)$	Inless Otherwise Specified)	Min.	Тур.	Max
g_{fs}	$V_{DS} = 20V, I_{D} = 0.5 \bullet I_{D25}, Note 1$	1.2	2.0	S
C _{iss}			1207	pF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		57	pF
C _{rss}			11	pF
t _{d(on)}	Resistive Switching Times		22	ns
t _r	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		25	ns
t _{d(off)}	$R_{\rm g} = 18\Omega$ (External)		70	ns
t,	n _g = 1052 (External)		32	ns
Q _{g(on)}			37	nC
Q _{gs}	$V_{GS} = 10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_{D} = 0.5 \cdot I_{D25}$		6	nC
\mathbf{Q}_{gd}			20	nC
R _{thJC}				1.0 °C/W
\mathbf{R}_{thCS}	TO-220		0.50	°C/W
	TO-247		0.21	°C/W

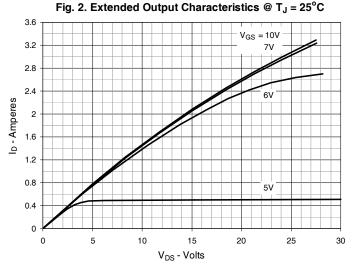
Source-Drain Diode

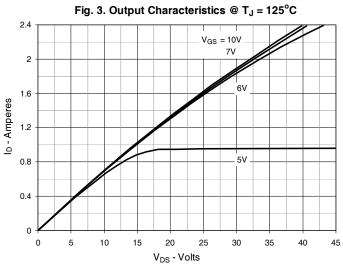
Symbol	Test Conditions	Chara	cteristic	Values	
$(T_J = 25^{\circ}C, L)$	Inless Otherwise Specified)	Min.	Тур.	Max	
Is	$V_{GS} = 0V$			2.4	Α
SM	Repetitive, pulse Width Limited by $T_{_{JM}}$			7.2	A
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.5	V
t _{rr}	$I_F = 2.4A, -di/dt = 100A/\mu s$		920		ns
	$V_R = 100V$				

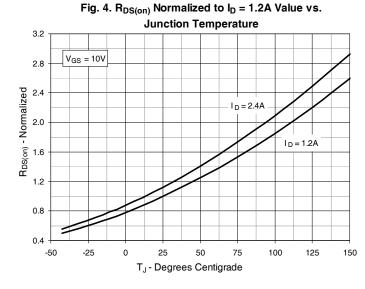
Note 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.

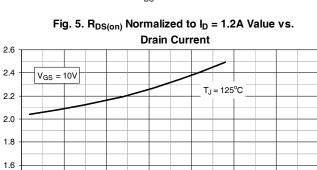










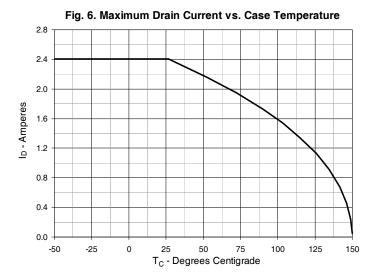


 $T_J = 25^{\circ}C$

2.5

3.0

3.5



1.0

1.5

2.0

I_D - Amperes

0.5

R_{DS(on)} - Normalized

1.4

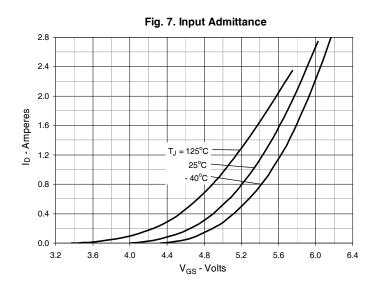
1.2

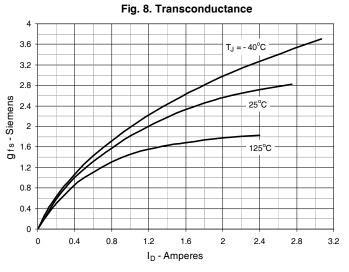
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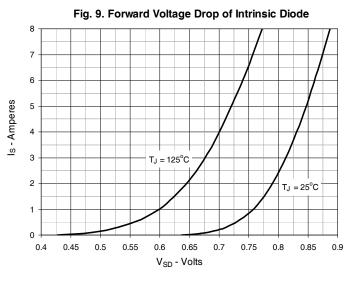
8.0

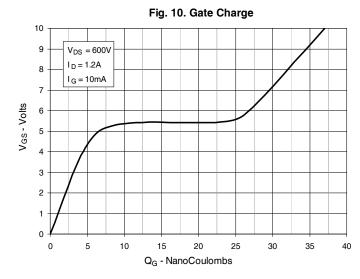
0.0

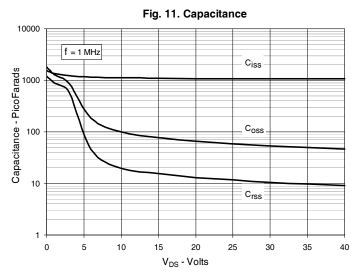


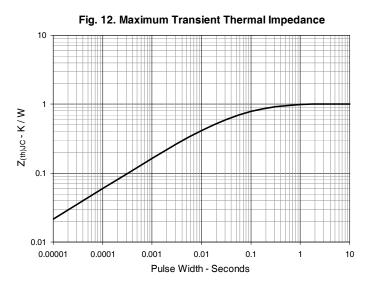








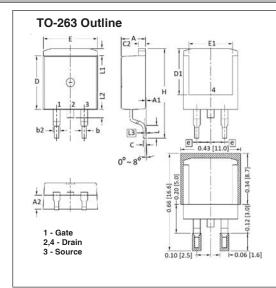




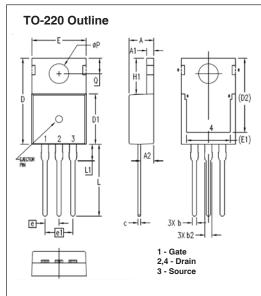
IXYS reserves the right to change limits, test conditions, and dimensions.



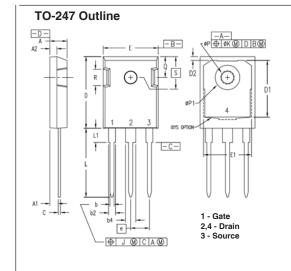
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SYM	INCHES		MILLIMETER	
SIM	MIN	MAX	MIN	MAX
Α	.170	.185	4.30	4.70
A1	.000	.008	0.00	0.20
A2	.091	.098	2.30	2.50
b	.028	.035	0.70	0.90
b2	.046	.060	1.18	1.52
С	.018	.024	0.45	0.60
C2	.049	.060	1.25	1.52
D	.340	.370	8.63	9.40
D1	.300	.327	7.62	8.30
E	.380	.410	9.65	10.41
E1	.270	.330	6.86	8.38
е	.100 BSC		2.54 BSC	
Н	.580	.620	14.73	15.75
L	.075	.105	1.91	2.67
L1	.039	.060	1.00	1.52
L2	_	.070	_	1.77
L3	.010 BSC		0.254	BSC



MYS	INCHES		MILLIMETERS	
21M	MIN	MAX	MIN	MAX
Α	.169	.185	4.30	4.70
A1	.047	.055	1.20	1.40
A2	.079	.106	2.00	2.70
Ь	.024	.039	0.60	1.00
b2	.045	.057	1.15	1.45
O	.014	.026	0.35	0.65
О	.587	.626	14.90	15.90
D1	.335	.370	8.50	9.40
(D2)	.500	.531	12.70	13.50
E	.382	.406	9.70	10.30
(E1)	.283	.323	7.20	8.20
е	.100 BSC		2.54 BSC	
e1	.200 BSC		5.08 BSC	
H1	.244	.268	6.20	6.80
٦	.492	.547	12.50	13.90
L1	.110	.154	2.80	3.90
ØΡ	.134	.150	3.40	3.80
Q	.106	.126	2.70	3.20



SYM	INCHES		MILLIMETERS	
STIVI	MIN	MAX	MIN	MAX
Α	.190	.205	4.83	5.21
Α1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
b	.045	.055	1.14	1.40
b2	.075	.087	1.91	2.20
b4	.115	.126	2.92	3.20
С	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
D1	.650	.690	16.51	17.53
D2	.035	.050	0.89	1.27
Ε	.620	.635	15.75	16.13
E1	.545	.565	13.84	14.35
е	.215	BSC	5.45 BSC	
J		.010		0.25
K		.025		0.64
L	.780	.810	19.81	20.57
L1	.150	.170	3.81	4.32
ØΡ	.140	.144	3.55	3.65
øP1	.275	.290	6.99	7.37
Q	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83
S	.242BSC 6.15BSC		BSC	

